#### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE8295AD uses advanced trench technology and design to provide excellent  $R_{\rm DS(ON)}$  with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

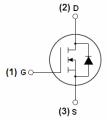
#### **General Features**

- $V_{DS} = 82V, I_D = 95A$  $R_{DS(ON)} < 8.0 \text{ m}\Omega @ V_{GS} = 10V$  (Typ:6.6mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for convertors and power controls
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply

100% UIS TESTED! 100% ΔVds TESTED!



#### Schematic diagram



Marking and pin assignment



TO-263-2L top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE8295AD	NCE8295AD	TO-263-2L	-	-	-

## Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	82	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	95	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	67	А
Pulsed Drain Current	I <sub>DM</sub>	320	А
Maximum Power Dissipation	P <sub>D</sub>	170	W
Derating factor		1.13	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	529	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>eJC</sub>	0.88	°C/W



# NCE8295AD

## Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	82	-	-	V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =82V,V <sub>GS</sub> =0V	-	-	1	μΑ	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA	
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	2.9	4	V	
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	6.6	8.0	mΩ	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	50	-	S	
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>		-	6800	-	PF	
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V, F=1.0MHz	-	353	-	PF	
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WIn2	-	261	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>		-	18	-	nS	
Turn-on Rise Time	t <sub>r</sub>	VDD=40V,RL=15 $\Omega$	-	12	-	nS	
Turn-Off Delay Time	t <sub>d(off)</sub>	RG=2.5Ω,VGS=10V	-	56	-	nS	
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS	
Total Gate Charge	Qg	\/ -40\/  -504	-	109.3	-	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =40V, $I_{D}$ =50A, $V_{GS}$ =10V	-	35.1	-	nC	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	25.8	-	nC	
Drain-Source Diode Characteristics			•				
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =95A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	95	Α	
Reverse Recovery Time	t <sub>rr</sub>	Tj=25°C,I <sub>F</sub> =100A	-		37	nS	
Reverse Recovery Charge	Qrr	di/dt=100A/µs <sup>(Note3)</sup>	-		58	nC	

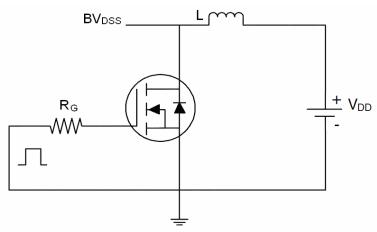
#### **Notes:**

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25  $^{\circ}\text{C}$  ,VDD=40V,VG=10V,L=0.5mH,Rg=25 $\Omega$

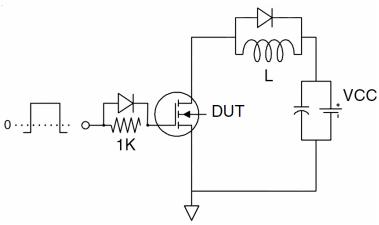


## **Test Circuit**

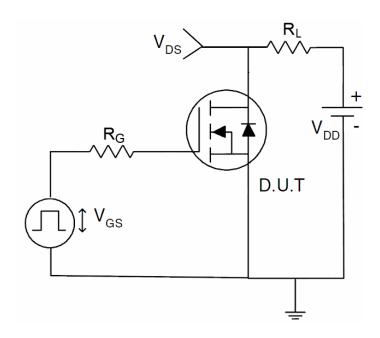
## 1) E<sub>AS</sub> Test Circuits



## 2) Gate Charge Test Circuit



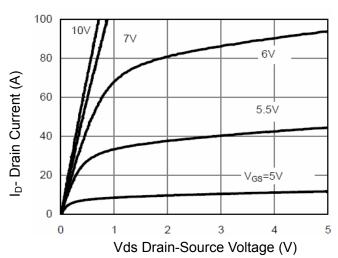
## 3) Switch Time Test Circuit



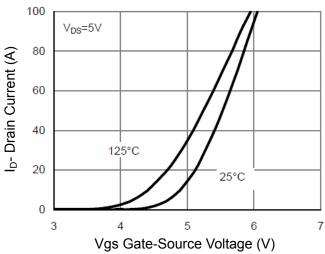
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### **Typical Electrical and Thermal Characteristics (Curves**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

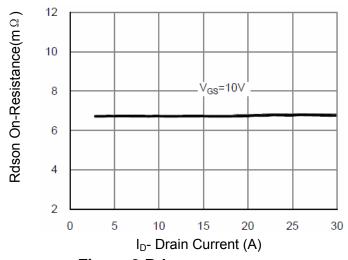
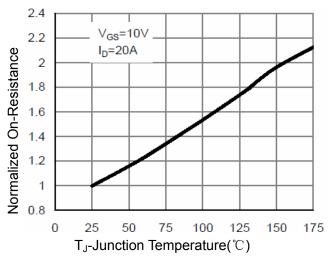


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

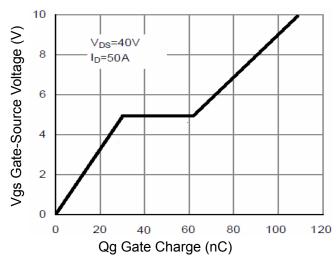


Figure 5 Gate Charge

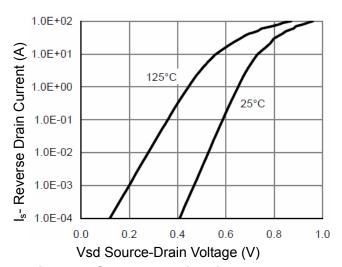


Figure 6 Source- Drain Diode Forward

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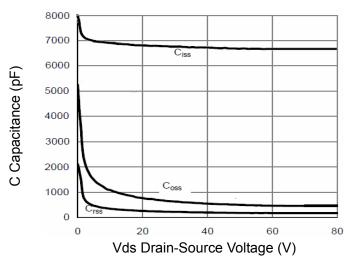


Figure 7 Capacitance vs Vds

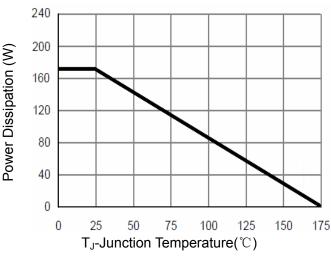


Figure 9 Power De-rating

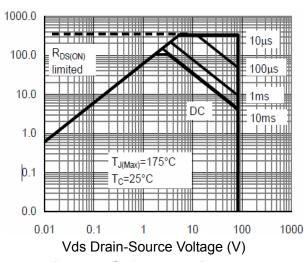


Figure 8 Safe Operation Area

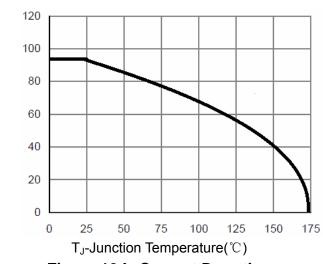
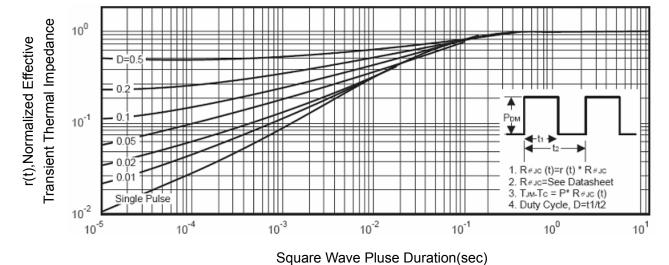


Figure 10 I<sub>D</sub> Current De-rating



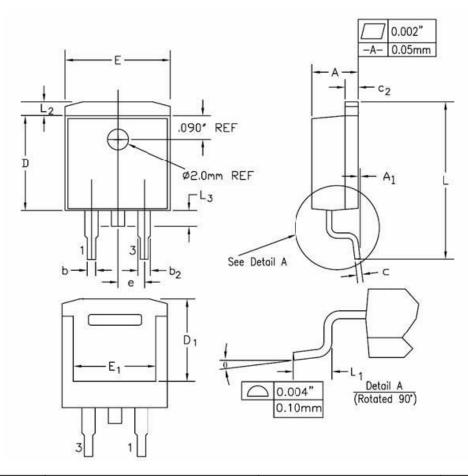
D- Drain Current (A)

Figure 11 Normalized Maximum Transient Thermal Impedance

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## **TO-263-2L Package Information**



SYMBOL	INCHES		MILLIM	NOTES	
STIVIDOL	MIN	MAX	MIN	MAX	NOTES
Α	0.170	0.180	4.32	4.57	
A1	-	0.010	-	0.25	
b	0.028	0.037	0.71	0.94	
b2	0.045	0.055	1.15	1.40	
С	0.018	0.024	0.46	0.61	
c2	0.048	0.055	1.22	1.40	
D	0.350	0.370	8.89	9.40	
D1	0.315	0.324	8.01	8.23	
E	0.395	0.405	10.04	10.28	
E1	0.310	0.318	7.88	8.08	
e	0.100 BSC.		2.54 BSC.		
L	0.580	0.620	14.73	15.75	
L1	0.090	0.110	2.29	2.79	
L2	0.045	0.055	1.15	1.39	
L3	0.050	0.070	1.27	1.77	
θ	0°	8°	0°	8°	



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NCE8295AD

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